

DATA SHEET

TEA5711; TEA5711T AM/FM stereo radio circuit

Product specification
Supersedes data of October 1992
File under Integrated Circuits, IC01

September 1994

Philips Semiconductors



PHILIPS

AM/FM stereo radio circuit

TEA5711; TEA5711T

FEATURES

- Wide supply voltage range: 1.8 or 2.1 to 12 V
- Low current consumption: 15 mA at AM, 16 mA at FM
- High selectivity with distributed IF gain
- LED driver for stereo indication
- High input sensitivity: 1.6 mV/m (AM), 2.0 μ V (FM) for 26 dB S/N
- Good strong signal behaviour: 10 V/m at AM, 500 mV at FM
- Low output distortion: 0.8% at AM, 0.3% at FM
- Signal level output
- Soft mute
- Signal dependent stereo

- Designed for simple and reliable printed-circuit board layout
- High impedance MOSFET input on AM.

APPLICATIONS

- Portable AM/FM stereo radio
- Mini/midi receiver sets
- Personal headphone radio.

DESCRIPTION

The TEA5711 is a high performance Bimos IC for use in AM/FM stereo radios. All necessary functions are integrated: from AM and FM front-end to AM detector and FM stereo output stages.

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | TYP. |
|------------------------|-------------------------------|--|------|------|------|--------------|
| V_P | dynamic supply voltage | | 1.8 | – | 12 | V |
| V_P | static supply voltage | | 2.1 | – | 12 | V |
| I_P | supply current | | | | | |
| | AM mode | | 11.9 | 15.0 | 18.9 | mA |
| | FM mode | | 13.5 | 16.5 | 20.2 | mA |
| T_{amb} | operating ambient temperature | | –15 | – | +60 | $^{\circ}$ C |
| AM performance | | | | | | |
| V_{in1} | RF sensitivity | | 40 | 55 | 70 | μ V |
| V_{28} | AF output voltage | | 36 | 45 | 70 | mV |
| THD | total harmonic distortion | | – | 0.8 | 2.0 | % |
| FM performance | | | | | | |
| V_{in3} | RF sensitivity | | 1.0 | 2.0 | 3.8 | μ V |
| V_{28} | AF output voltage | | 50 | 61 | 72 | mV |
| THD | total harmonic distortion | | – | 0.3 | 0.8 | % |
| MPX performance | | | | | | |
| α_{CS} | channel separation | | 26 | 30 | – | dB |
| A_{MPX} | MPX voltage gain | V_{AF-L}/V_{in9} ; S5 in position MONO | –1.5 | 0 | +1.0 | dB |
| THD | total harmonic distortion | | – | 0.5 | 1.0 | % |

ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | |
|-------------|---------|--|----------|
| | NAME | DESCRIPTION | VERSION |
| TEA5711 | SDIP32 | plastic shrink dual in-line package; 32 leads (400 mil) | SOT232-1 |
| TEA5711T | SO32 | plastic small outline package; 32 leads; body width 7.5 mm | SOT287-1 |

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BLOCK DIAGRAM

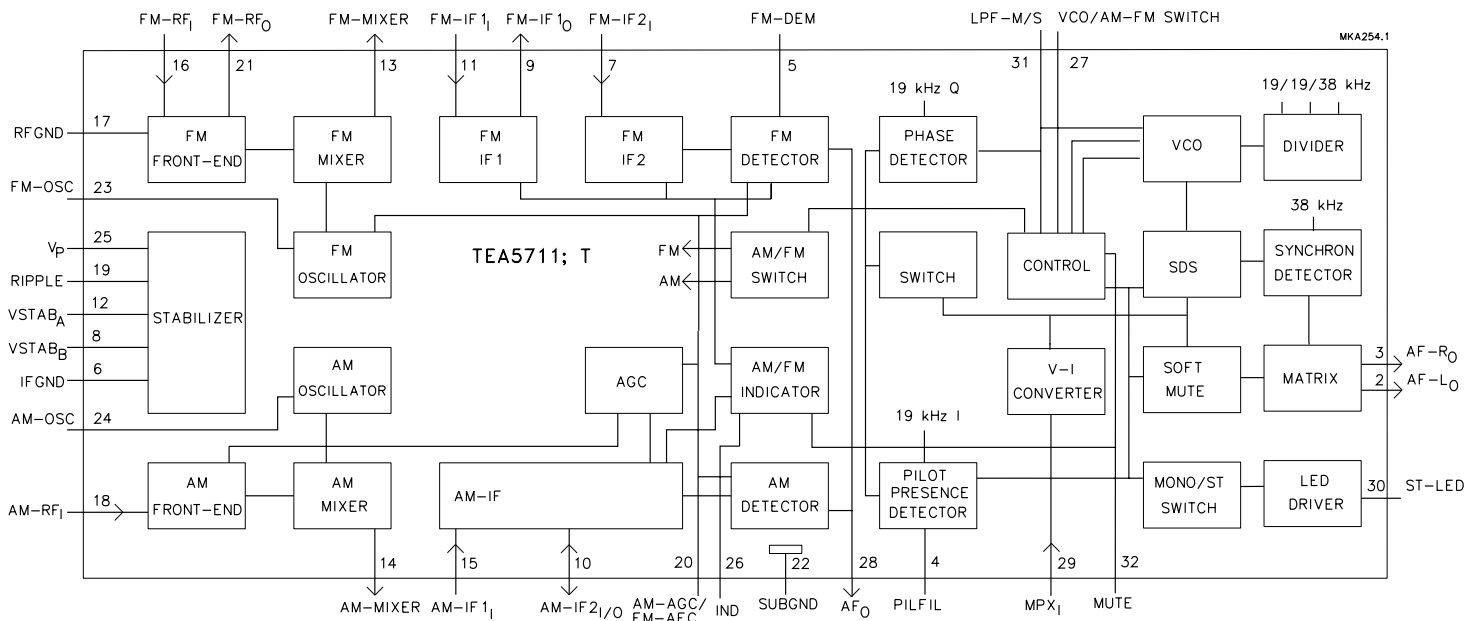


Fig.1 Block diagram.

AM/FM stereo radio circuit

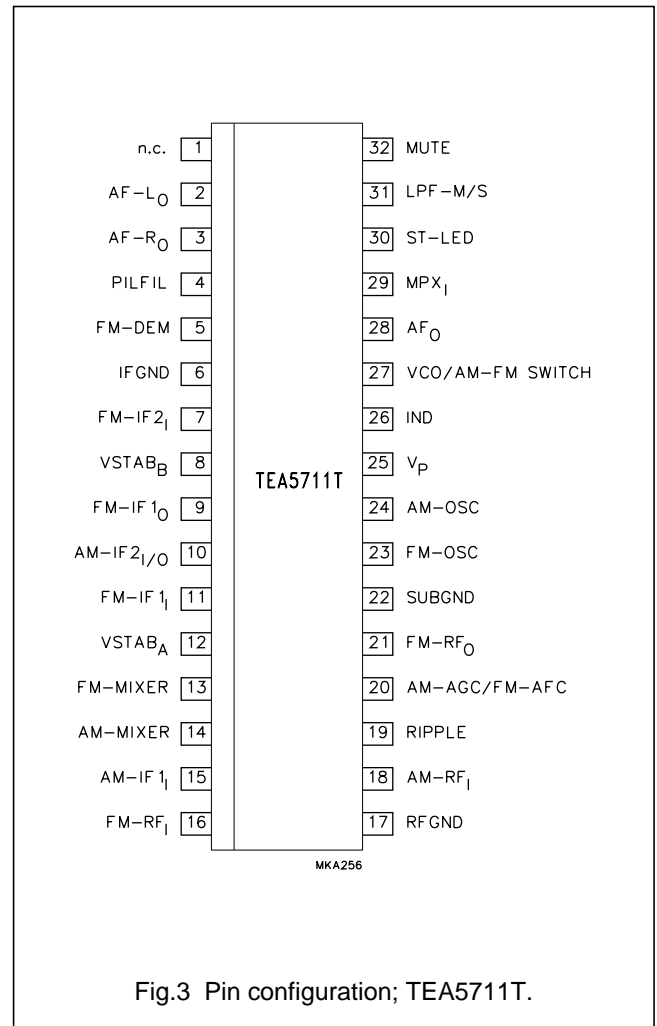
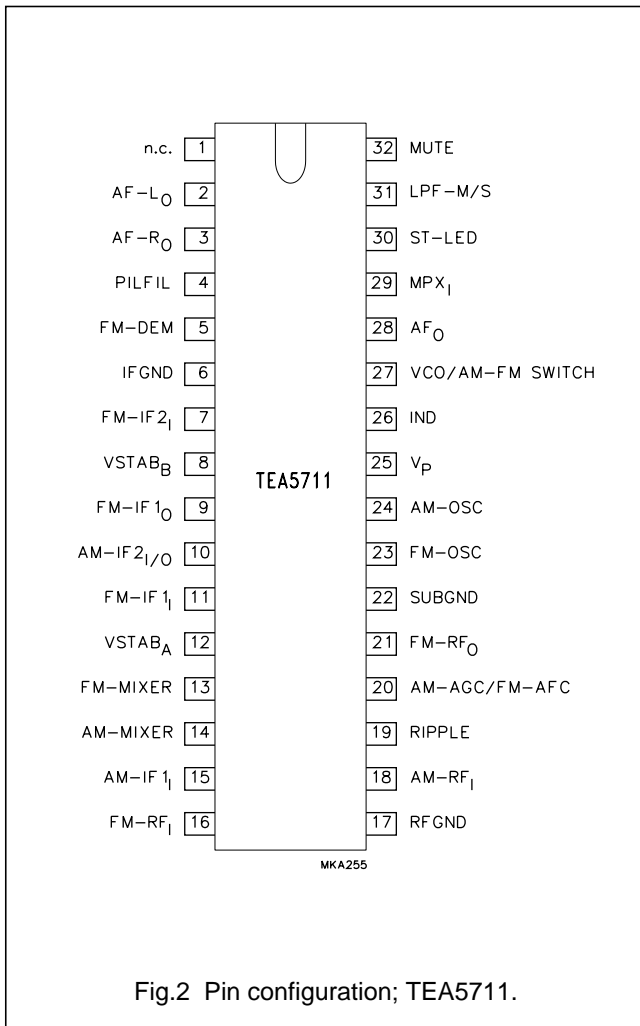
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PINNING

| SYMBOL | PIN | DESCRIPTION |
|-----------------------|-----|--|
| n.c. | 1 | not connected |
| AF-L _O | 2 | left channel audio output (output impedance typ. 4.3 k Ω) |
| AF-R _O | 3 | right channel audio output (output impedance typ. 4.3 k Ω) |
| PILFIL | 4 | pilot detector filter pin |
| FM-DEM | 5 | ceramic discriminator pin |
| IFGND | 6 | ground of IF, detector and MPX stages |
| FM-IF _{2I} | 7 | second FM-IF input (input impedance typ. 330 Ω) |
| VSTAB _B | 8 | stabilized internal supply voltage (B) |
| FM-IF _{1O} | 9 | first FM-IF output (output impedance typ. 330 Ω) |
| AM-IF _{2I/O} | 10 | input/output to IFT; output: current source |
| FM-IF _{1I} | 11 | first FM-IF input (input impedance typ. 330 Ω) |
| VSTAB _A | 12 | stabilized internal supply voltage (A) |
| FM-MIXER | 13 | output to ceramic IF filter (output impedance typ. 330 Ω) |
| AM-MIXER | 14 | open-collector output to IFT |
| AM-IF _{1I} | 15 | input from IFT or ceramic filter (input impedance typ. 3 k Ω) |
| FM-RF _I | 16 | FM-RF aerial input (input impedance typ. 50 Ω) |
| RFGND | 17 | FM-RF ground |
| AM-RF _I | 18 | parallel tuned AM aerial circuit to ground (total input capacitance typ. 3 pF) |
| RIPPLE | 19 | ripple capacitor pin |
| AM-AGC/FM-AFC | 20 | AGC/AFC capacitor pin |
| FM-RF _O | 21 | parallel tuned FM-RF circuit to ground |
| SUBGND | 22 | substrate and RF ground |
| FM-OSC | 23 | parallel tuned FM-oscillator circuit to ground |
| AM-OSC | 24 | parallel tuned AM-oscillator circuit to ground |
| V _P | 25 | positive supply voltage |
| IND | 26 | signal level output |
| VCO/AM-FM SWITCH | 27 | VCO and switch terminal: open for AM; ground for FM |
| AF _O | 28 | AM/FM AF output (output impedance typ. 5 k Ω) |
| MPX _I | 29 | input for stereo decoder (input impedance typ. 180 k Ω) |
| ST-LED | 30 | stereo indicator |
| LPF-M/S | 31 | pin for loop-filter and mono/stereo switch |
| MUTE | 32 | mute pin |

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AM/FM stereo radio circuit

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FUNCTIONAL DESCRIPTION

The AM circuit incorporates a double balanced mixer, a one pin low-voltage oscillator (up to 30 MHz) a field-strength indicator output and is designed for distributed selectivity.

The AM input is designed to be connected to the top of a tuned circuit. AGC controls the IF amplification and for large signals it lowers the input impedance.

The first AM selectivity can be an IFT as well as an IFT combined with a ceramic filter; the second one is an IFT.

The FM circuit incorporates a tuned RF stage, a double balanced mixer, a one-pin oscillator, a field-strength indicator output and is designed for distributed IF ceramic filters. The FM quadrature detector uses a ceramic resonator.

The PLL stereo decoder incorporates a signal dependent stereo circuit, a soft-mute circuit and a stereo indicator LED driver.

Supply voltage behaviour

The TEA5711 incorporates internal stabilized power supplies. The maximum supply voltage is 12 V, the minimum voltage can go down temporarily to 1.8 V without any loss in performance.

Due to the capacitor at pin 19 (RIPPLE) the IC gives excellent performance, even when the actual supply voltage at pin 25 (V_P) drops below the voltage at pin 19 (RIPPLE).

Figures 4, 5 and 6 show that V_{stab} , which is dominant for the overall IC performance, remains unaffected, even if V_P drops down to 1.8 V or less. In this typical example the static or average V_P is equal to 2.5 V. Dips in V_{stab} appear only when the peak-to-peak value of the AC-component of $V_P > 2$ V, i.e. when the dynamic value of V_P drops down to 1.5 V for a short moment.

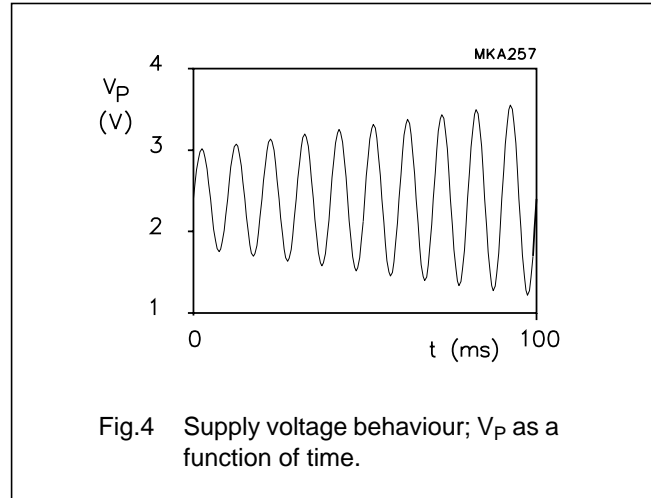


Fig.4 Supply voltage behaviour; V_P as a function of time.

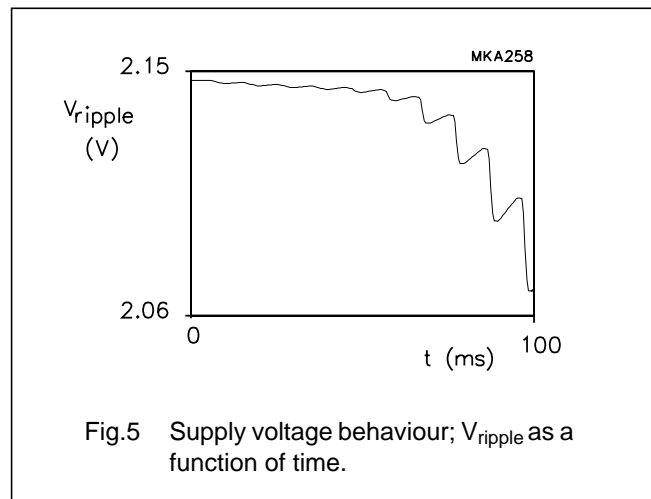


Fig.5 Supply voltage behaviour; V_{ripple} as a function of time.

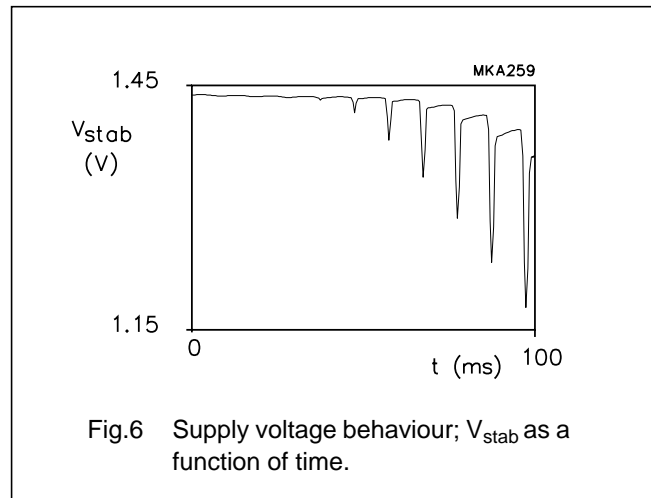


Fig.6 Supply voltage behaviour; V_{stab} as a function of time.

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT |
|-----------|-------------------------------|------|------|------|
| V_P | supply voltage | 0 | 12 | V |
| T_{stg} | storage temperature | -55 | +150 | °C |
| T_{amb} | operating ambient temperature | -15 | +60 | °C |
| T_j | junction temperature | -15 | +150 | °C |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | VALUE | UNIT |
|---------------|---|-------|------|
| $R_{th\ j-a}$ | thermal resistance from junction to ambient in free air | | |
| | SDIP32 | 54 | K/W |
| | SO32 | 68 | K/W |

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CIRCUIT DESIGN DATA

| PIN NO. | PIN SYMBOL | DC PIN VOLTAGE (V) | | EQUIVALENT CIRCUIT |
|---------|-----------------------------|--------------------|------|--------------------|
| | | AM | FM | |
| 1 | n.c. | - | - | |
| 2 | AF-L _O output | 0.65 | 0.65 | <p>MKA268.1</p> |
| 3 | AF-R _O output | 0.65 | 0.65 | <p>MKA268.1</p> |
| 4 | PILFIL | 0.95 | 0.95 | <p>MKA269.1</p> |
| 5 | FM-DEM | - | 1.0 | <p>MKA270.1</p> |
| 6 | IFGND | 0 | 0 | |

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| PIN NO. | PIN SYMBOL | DC PIN VOLTAGE (V) | | EQUIVALENT CIRCUIT |
|---------|---------------------------------------|--------------------|------|--------------------|
| | | AM | FM | |
| 7 | FM-IF _{2I} input | – | 0.73 | |
| 8 | VSTAB _B | 1.4 | 1.4 | |
| 9 | FM-IF _{1O} output | – | 0.69 | |
| 10 | AM-IF _{2I/O} input/output | 1.4 | 1.4 | |

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| PIN NO. | PIN SYMBOL | DC PIN VOLTAGE (V) | | EQUIVALENT CIRCUIT |
|---------|-----------------------------|--------------------|------|--------------------|
| | | AM | FM | |
| 11 | FM-IF ₁ input | – | 0.73 | |
| 12 | VSTAB _A | 1.4 | 1.4 | |
| 13 | FM-MIXER output | – | 1.0 | |
| 14 | AM-MIXER output | 1.4 | 1.4 | |

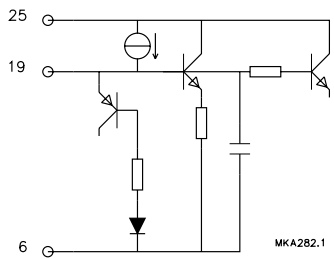
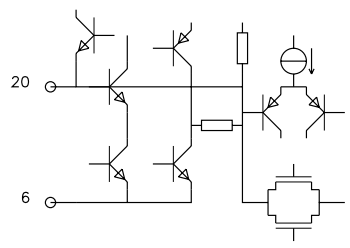
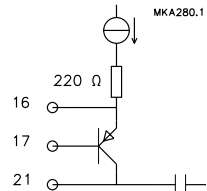
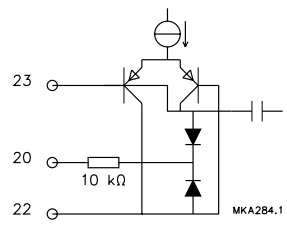
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| PIN NO. | PIN SYMBOL | DC PIN VOLTAGE (V) | | EQUIVALENT CIRCUIT |
|---------|-----------------------------|--------------------|------|--------------------|
| | | AM | FM | |
| 15 | AM-IF ₁ input | 1.4 | 1.4 | |
| 16 | FM-RF ₁ input | — | 0.73 | |
| 17 | RFGND | 0 | 0 | |
| 18 | AM-RF ₁ input | 0 | 0 | |

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| PIN NO. | PIN SYMBOL | DC PIN VOLTAGE (V) | | EQUIVALENT CIRCUIT |
|---------|--------------------|--------------------|-----|---|
| | | AM | FM | |
| 19 | RIPPLE | 2.1 | 2.1 |  |
| 20 | AM-AGC/ FM-AFC | 0.1 | 0.7 |  |
| 21 | FM-RF _O | 0 | 0 |  |
| 22 | SUBGND | 0 | 0 | |
| 23 | FM-OSC | 0 | 0 |  |

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| PIN NO. | PIN SYMBOL | DC PIN VOLTAGE (V) | | EQUIVALENT CIRCUIT |
|---------|----------------------|--------------------|------|--------------------|
| | | AM | FM | |
| 24 | AM-OSC | 0 | 0 | |
| 25 | V _P | 3.0 | 3.0 | |
| 26 | IND output | 3.0 | 3.0 | |
| 27 | VCO and AM/FM switch | 1.3 | 0.95 | |
| 28 | AF output | 0.6 | 0.7 | |

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| PIN NO. | PIN SYMBOL | DC PIN VOLTAGE (V) | | EQUIVALENT CIRCUIT |
|---------|------------|--------------------|------|--------------------|
| | | AM | FM | |
| 29 | MPX input | 1.23 | 1.23 | <p>MKA289.1</p> |
| 30 | ST-LED | 3.0 | 3.0 | <p>MKA290</p> |
| 31 | LPF-M/S | 0.1 | 0.8 | <p>MKA291.1</p> |
| 32 | MUTE | 0.7 | 0.7 | <p>MKA292</p> |

AM/FM stereo radio circuit

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AM CHARACTERISTICS

$f_i = 1$ MHz; $m = 0.3$; $f_m = 1$ kHz; $V_P = 3.0$ V; measured in Fig.7 with S1 in position B, S2 in position A and S7 in position A; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------|---------------------------|---------------------------------------|------|------|------|---------|
| I_P | supply current | no input signal | 11.9 | 15.0 | 18.9 | mA |
| C_i | input capacitance | $V_{20} = 0.2$ V | – | 3 | – | pF |
| G_c | front-end conversion gain | $V_{20} = 0.2$ V | 1.8 | 3.3 | 5.0 | |
| V_{in1} | RF sensitivity | S/N = 26 dB | 40 | 55 | 70 | μ V |
| V_{in2} | IF sensitivity | $V_{28} = 30$ mV; S1 in position A | 0.13 | 0.2 | 0.45 | mV |
| V_{28} | AF output voltage | $V_{in2} = 3.16$ mV; S1 in position A | 36 | 45 | 70 | mV |
| THD | total harmonic distortion | $V_{in1} = 1$ mV | – | 0.8 | 2.0 | % |
| V_{in1} | large signal handling | $m = 0.8$; THD $\leq 8\%$ | 150 | 300 | – | mV |
| I_{IND} | indicator current | $V_{in2} = 100$ mV; S1 in position A | 120 | 170 | 230 | μ A |
| I_{INDOFF} | indicator OFF current | $V_{in2} = 0$ V; S1 in position A | – | 0 | 10 | μ A |

FM CHARACTERISTICS

$f_i = 100$ MHz; $\Delta f = 22.5$ kHz; $f_m = 1$ kHz; $V_P = 3.0$ V; measured in Fig.7 with S1 in position B, S2 in position A and S7 in position A; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|------------------|---------------------------|---|------|------|------|---------|
| I_P | supply current | no input signal | 13.5 | 16.5 | 20.2 | mA |
| V_{in3} | RF limiting sensitivity | $V_{28} = -3$ dB | 0.4 | 1.2 | 3.8 | μ V |
| V_{in3} | RF sensitivity | S/N = 26 dB | 1.0 | 2.0 | 3.8 | μ V |
| V_{11}/V_{in3} | front-end voltage gain | $V_{in3} \leq 1$ mV; including ceramic filter K1 | 12 | 18 | 22 | dB |
| V_{in4} | IF sensitivity | S2 in position B; $V_{28} = -3$ dB | – | 20 | 30 | μ V |
| V_{28} | AF output voltage | $V_{in3} = 1$ mV | 50 | 61 | 72 | mV |
| THD | total harmonic distortion | $V_{in3} = 1$ mV; $\Delta f = 22.5$ kHz | – | 0.3 | 0.8 | % |
| V_{in3} | large signal handling | THD $\leq 5\%$ | – | 500 | – | mV |
| I_{IND} | indicator current | $V_{in4} = 100$ mV; S2 in position B | 190 | 255 | 320 | μ A |
| I_{INDOFF} | indicator OFF current | $V_{in4} = 0$ V; S2 in position B | – | 0 | 2 | μ A |

STEREO DECODER CHARACTERISTICS

$f_i = 1$ kHz; $V_{in9(L+R)} = 195$ mV; pilot = 20 mV; $V_P = 3.0$ V; measured in Fig.7 with S1 in position B, S2 in position A, S6 in position A, S7 in position A and S5 in position STEREO; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-----------------|-------------------------------------|------------------------------|------|------|------|------|
| A_{MPX} | MPX voltage gain V_{AF-L}/V_{in9} | S5 in position MONO | -1.5 | 0 | +1.0 | dB |
| THD | total harmonic distortion | | – | 0.5 | 1.0 | % |
| (S+N)/N | signal plus noise-to-noise ratio | pilot = 20 mV | – | 74 | – | dB |
| α_{cs} | channel separation | L = 1; R = 0 or L = 0; R = 1 | 26 | 30 | – | dB |
| SC | stereo control | $V_{in3} = 120$ μ V | – | 30 | – | dB |
| | | $V_{in3} = 10$ μ V | – | 1 | – | dB |
| α_{MUTE} | AF output signal suppression | $V_{in3} \leq 2$ μ V | – | 20 | – | dB |

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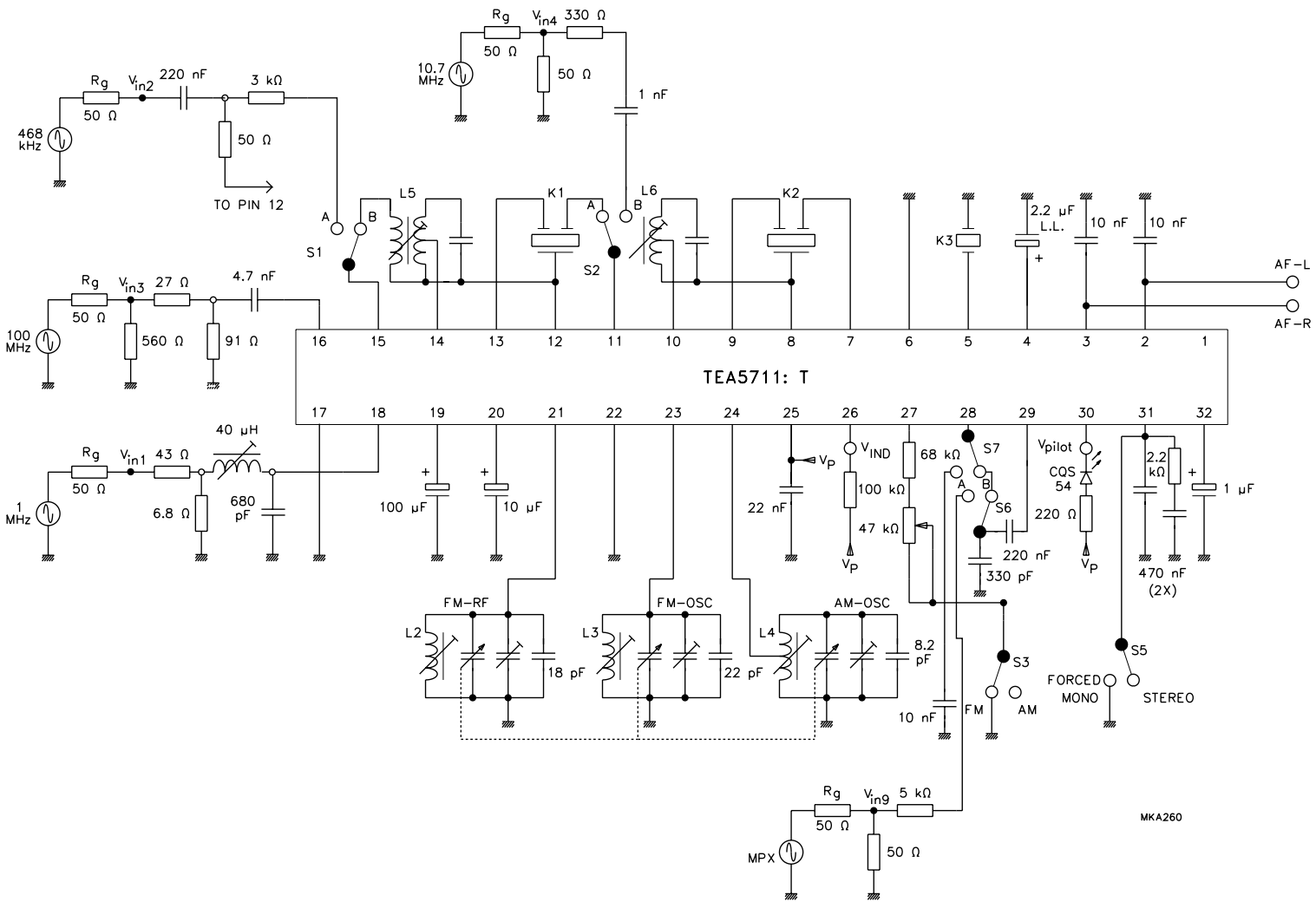


Fig.7 Test circuit.

MKA260

AM/FM stereo radio circuit

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APPLICATION INFORMATION

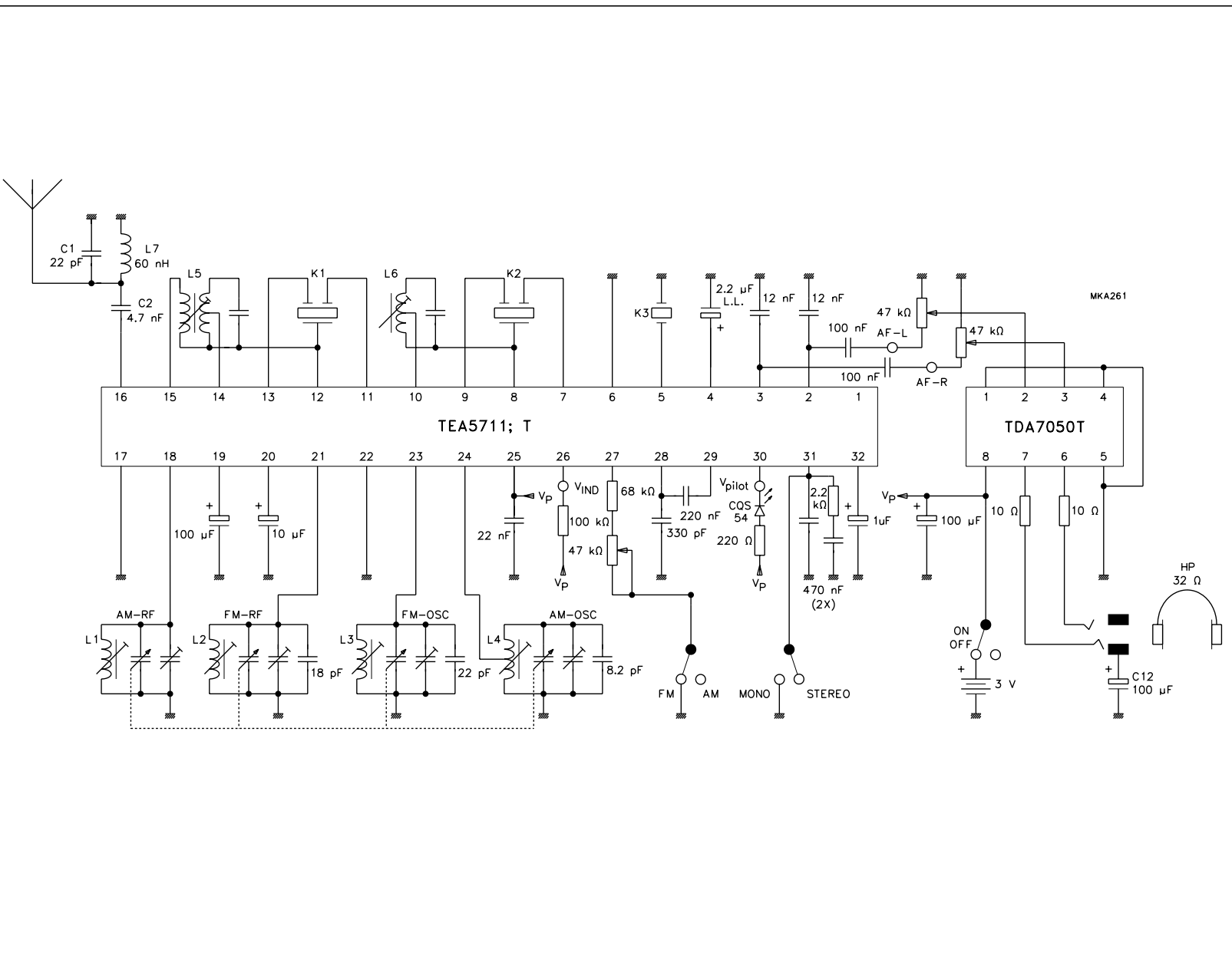
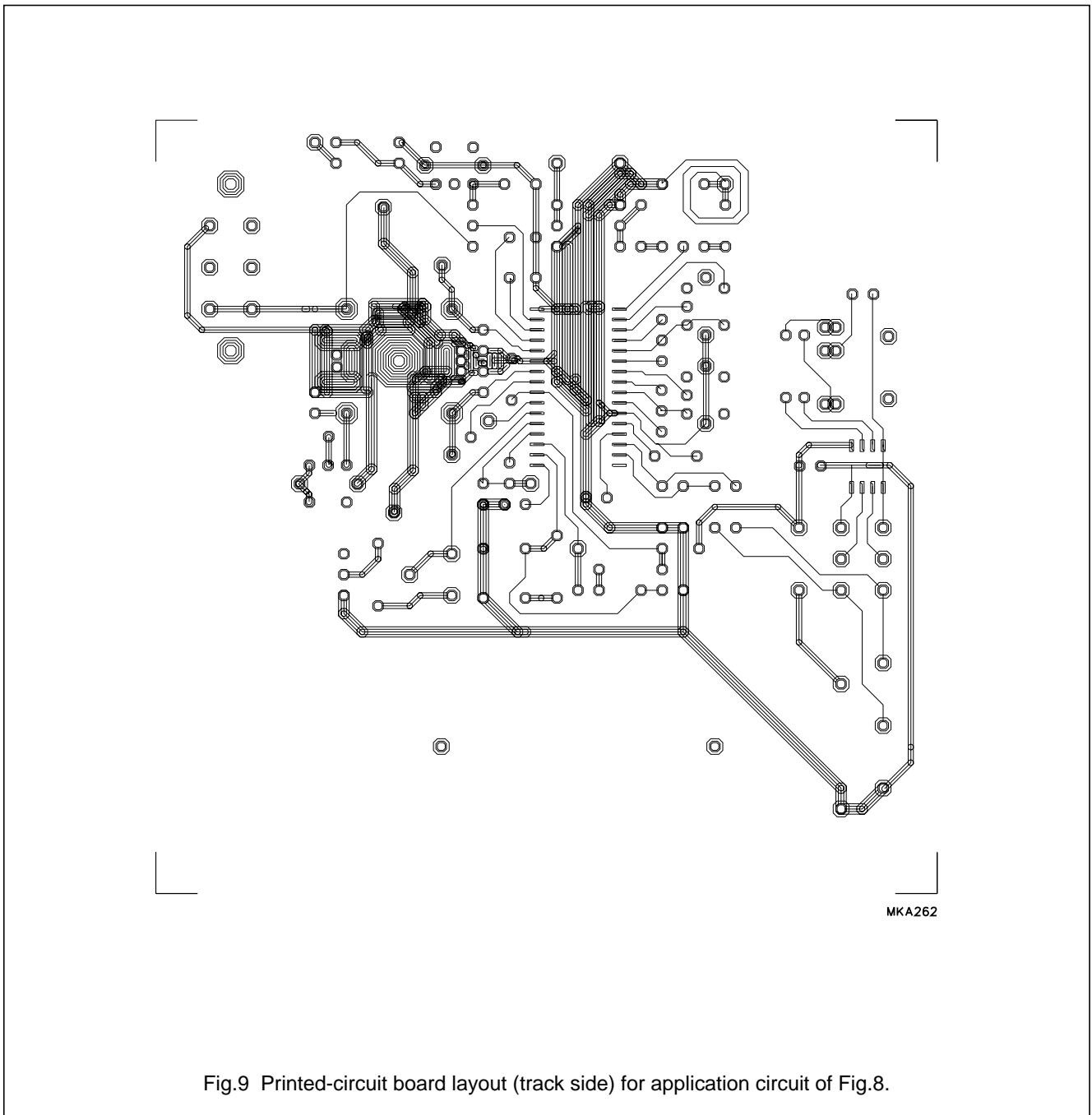


Fig.8 Application circuit of TEA5711 (AM: 522 to 1611 kHz, FM: 87.5 to 108 MHz) with stereo headphone amplifier TDA7050T.

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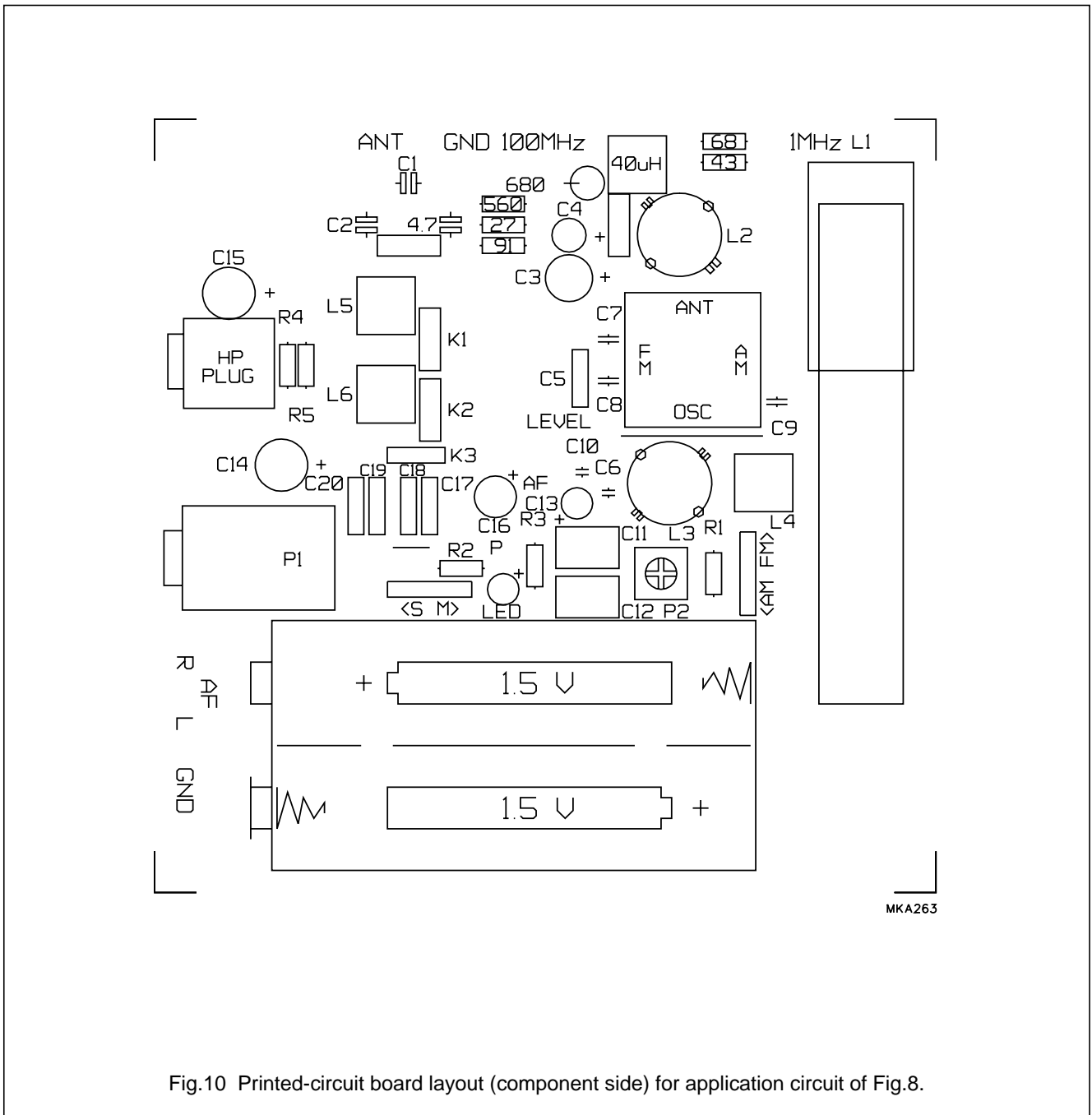


Fig.10 Printed-circuit board layout (component side) for application circuit of Fig.8.

AM/FM stereo radio circuit

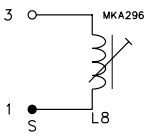
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Components for Figs 7 and 8

| NUMBER | TYPE | DESCRIPTION | CIRCUIT |
|--------------|-----------|---|---------|
| Coils | | | |
| L1 | AM-AERIAL | ferroceptor length = 6 cm L1-2 = 625 μ H N1-2 = 105 turns unloaded Q | |
| L2 | FM-RF | L1-2 = 66 nH N1-2 = 2.5 turns unloaded Q = 150T TOKO type S18 TOKO number 301SS-0200 | |
| L3 | FM-OSC | L1-2 = 40 nH N1-2 = 1.5 turns unloaded Q = 150 TOKO type S18 TOKO number 301SS-0100 | |
| L4 | AM-OSC | L1-3 = 270 μ H N1-2 = 18 N2-3 = 70 unloaded Q = 100 wire diameter 0.07 mm TOKO type 7P material TOKO 7BRS | |
| L5 | AM-IF1 | L1-3 = 625 μ H N1-2 = 17 turns N2-3 = 141 turns N4-6 = 10 turns C1-3 = 180 pF unloaded Q = 90 wire diameter 0.07 mm TOKO type 7P material TOKO 7MCS | |
| L6 | AM-IF2 | L1-3 = 625 μ H N1-2 = 28 turns N2-3 = 130 turns C1-3 = 180 pF unloaded Q = 90 wire diameter 0.07 mm TOKO type 7P material TOKO 7MCS | |
| L7 | FM-AERIAL | printcoil L1-2 = 60 nH N1-2 = 2.5 turns | |

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| NUMBER | TYPE | DESCRIPTION | CIRCUIT |
|------------------------|---------|--|---|
| L8 | AM-RF | test circuit only: L1-3 = 40 μ H N1-3 = 34 turns unloaded Q = 85 wire diameter 0.09 mm TOKO type 7P material TOKO 7BRS |  |
| Ceramic filters | | | |
| K1 | FM-IF1 | Murata SFE 10.7 MS 2 | |
| K2 | FM-IF2 | Murata SFE 10.7 MS 2 | |
| K3 | FM-DET | Murata CDA 10.7 MC 40 | |
| Capacitors | | | |
| C1 | VARICON | AM: 140/82 pF FM: 2 \times 20 pF trimmer: 4 \times 8 pF TOKO type number HU-22124 | |

Application remarks

- Short circuiting: **all** pins are short-circuit proof except **pin 16** (FM-RF₁) with respect to the supply voltage pin.
- For an example of printed-circuit board layout: see Figs 9 and 10.
- Align VCO with aerial signal present.

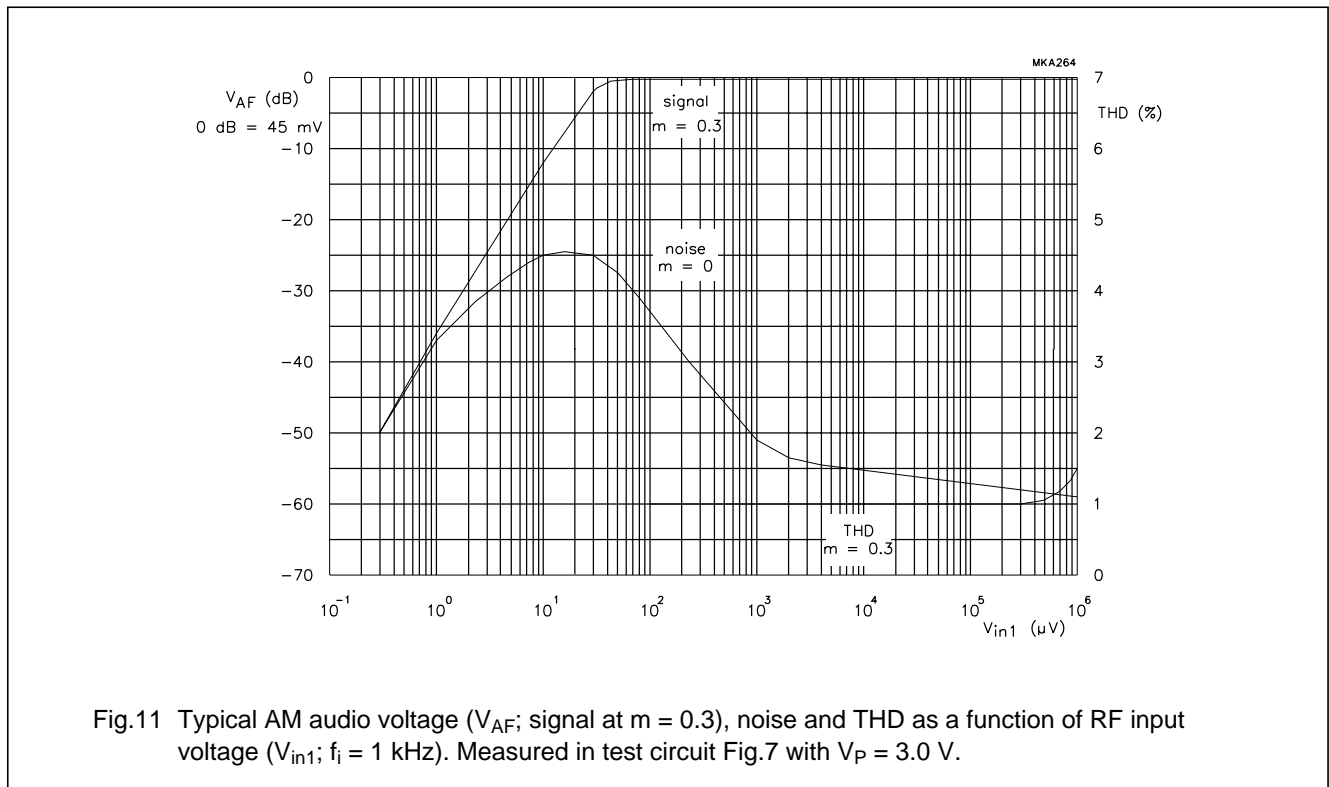


Fig.11 Typical AM audio voltage (V_{AF} ; signal at $m = 0.3$), noise and THD as a function of RF input voltage (V_{in1} ; $f_i = 1$ kHz). Measured in test circuit Fig.7 with $V_P = 3.0$ V.

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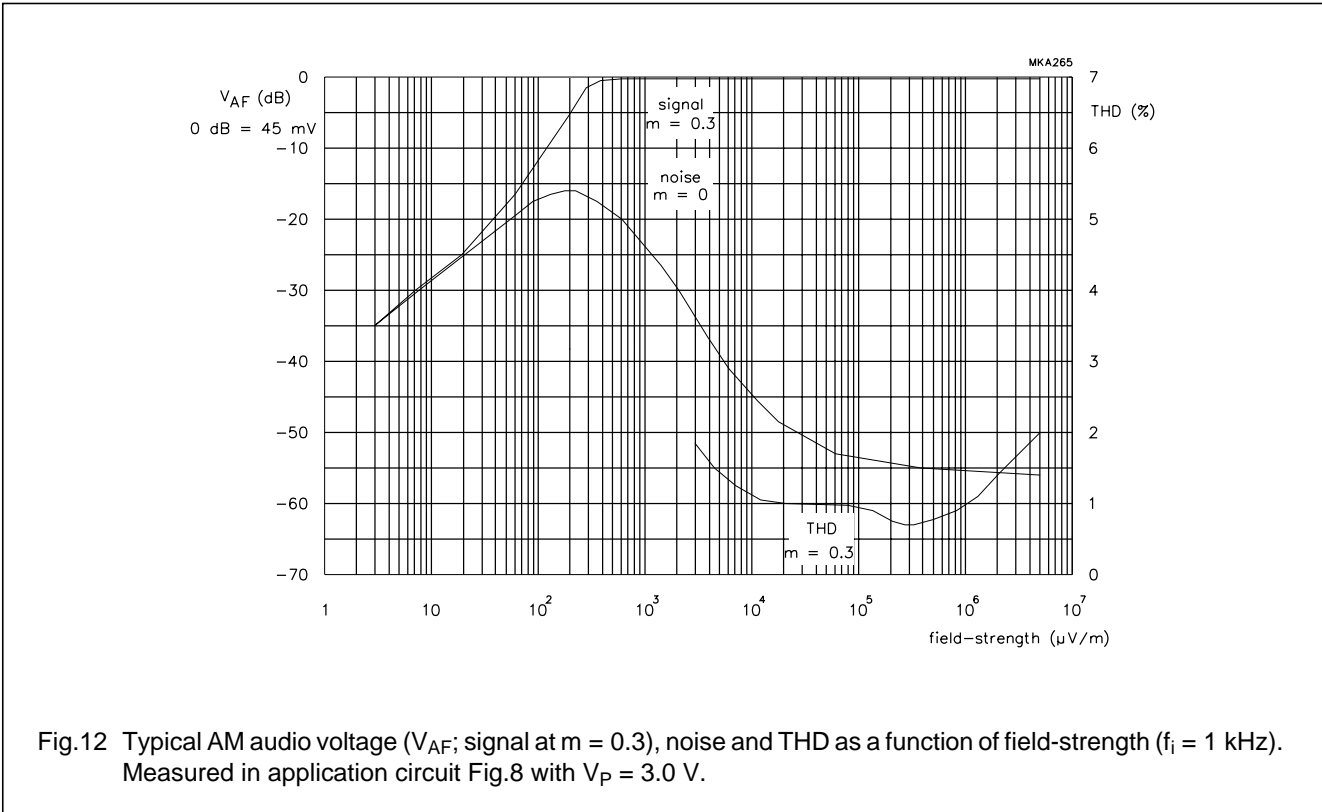


Fig. 12 Typical AM audio voltage (V_{AF} ; signal at $m = 0.3$), noise and THD as a function of field-strength ($f_i = 1$ kHz). Measured in application circuit Fig.8 with $V_P = 3.0$ V.

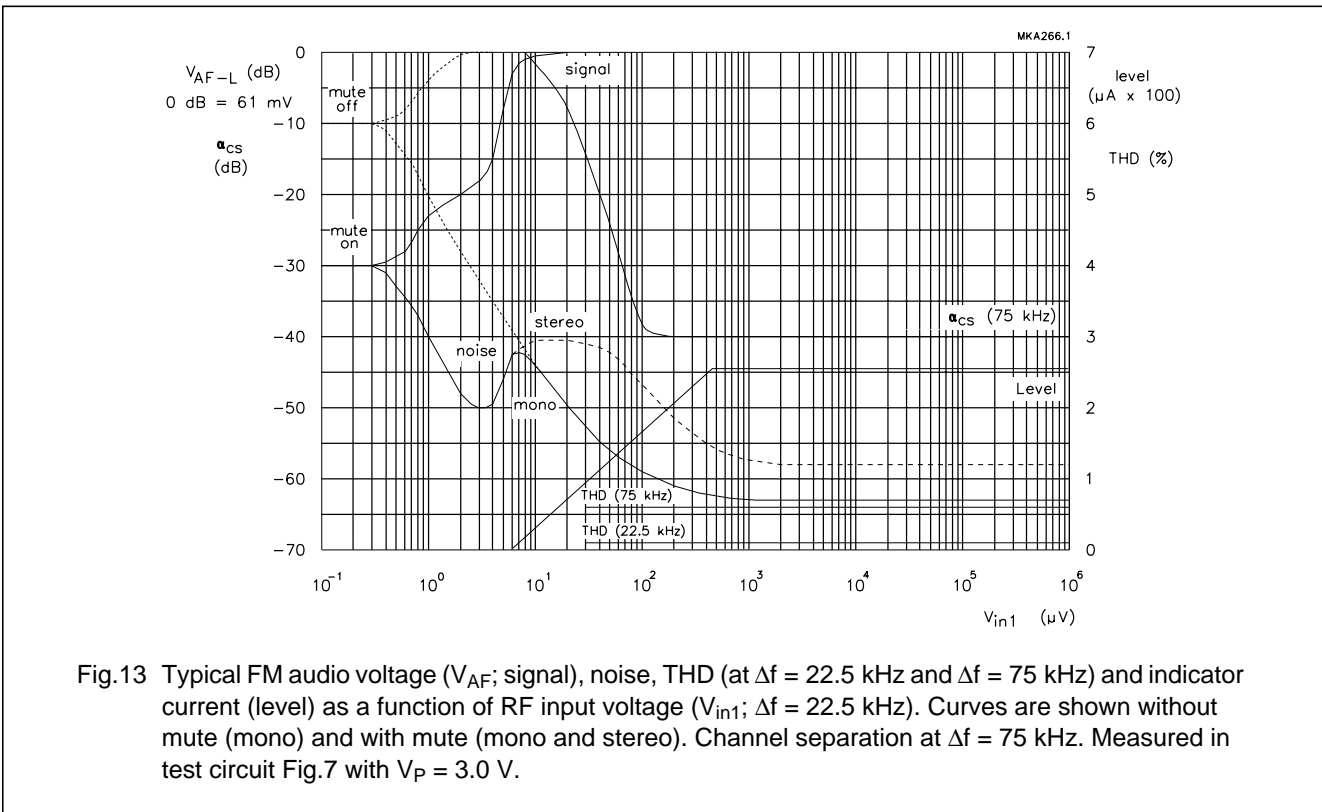
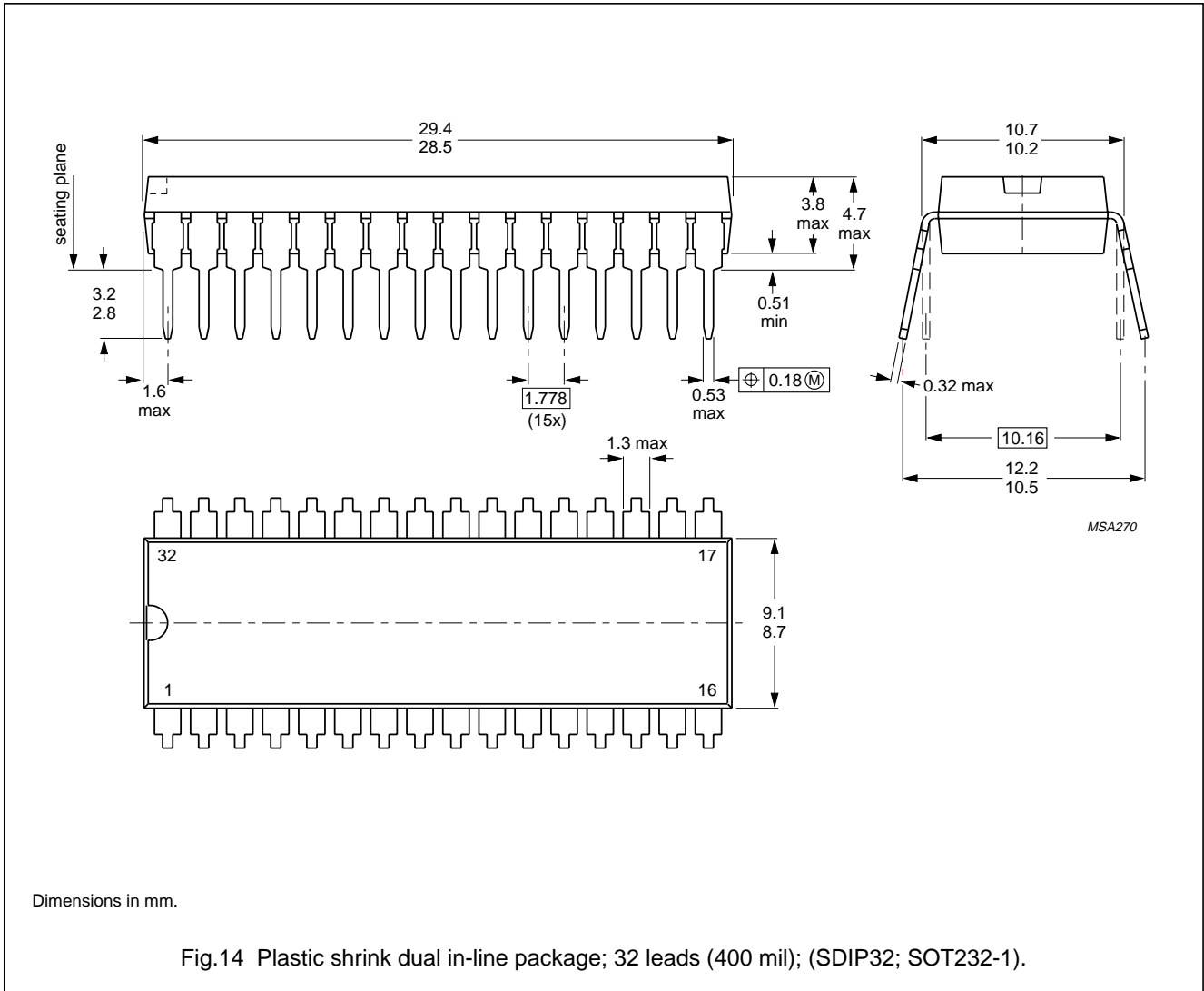


Fig. 13 Typical FM audio voltage (V_{AF} ; signal), noise, THD (at $\Delta f = 22.5$ kHz and $\Delta f = 75$ kHz) and indicator current (level) as a function of RF input voltage (V_{in1} ; $\Delta f = 22.5$ kHz). Curves are shown without mute (mono) and with mute (mono and stereo). Channel separation at $\Delta f = 75$ kHz. Measured in test circuit Fig.7 with $V_P = 3.0$ V.

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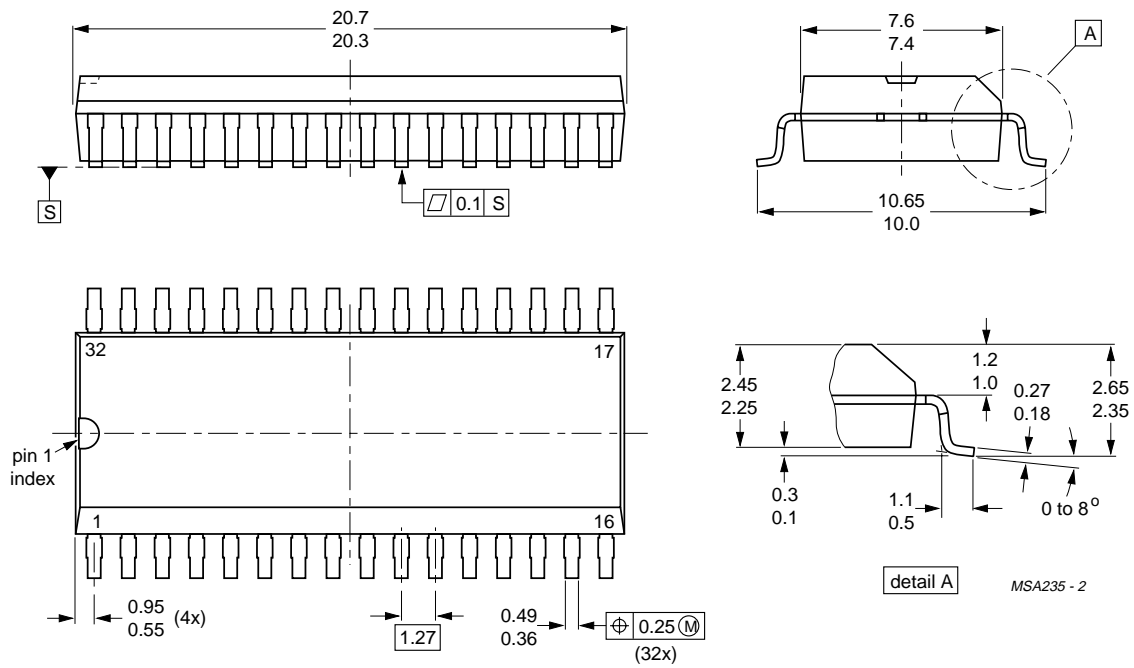
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PACKAGE OUTLINES



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Dimensions in mm.

Fig.15 Plastic small outline package; 32 leads; body width 7.5 mm (SO32; SOT287-1).

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SOLDERING**Plastic dual in-line packages**

BY DIP OR WAVE

The maximum permissible temperature of the solder is 260 °C; this temperature must not be in contact with the joint for more than 5 s. The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified storage maximum. If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

REPAIRING SOLDERED JOINTS

Apply the soldering iron below the seating plane (or not more than 2 mm above it). If its temperature is below 300 °C, it must not be in contact for more than 10 s; if between 300 and 400 °C, for not more than 5 s.

Plastic small-outline packages

BY WAVE

During placement and before soldering, the component must be fixed with a droplet of adhesive. After curing the adhesive, the component can be soldered. The adhesive can be applied by screen printing, pin transfer or syringe dispensing.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder bath is 10 s, if allowed to cool to less than 150 °C within 6 s. Typical dwell time is 4 s at 250 °C.

A modified wave soldering technique is recommended using two solder waves (dual-wave), in which a turbulent wave with high upward pressure is followed by a smooth laminar wave. Using a mildly-activated flux eliminates the need for removal of corrosive residues in most applications.

BY SOLDER PASTE REFLOW

Reflow soldering requires the solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the substrate by screen printing, stencilling or pressure-syringe dispensing before device placement.

Several techniques exist for reflowing; for example, thermal conduction by heated belt, infrared, and vapour-phase reflow. Dwell times vary between 50 and 300 s according to method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 min. at 45 °C.

REPAIRING SOLDERED JOINTS (BY HAND-HELD SOLDERING IRON OR PULSE-HEATED SOLDER TOOL)

Fix the component by first soldering two, diagonally opposite, end pins. Apply the heating tool to the flat part of the pin only. Contact time must be limited to 10 s at up to 300 °C. When using proper tools, all other pins can be soldered in one operation within 2 to 5 s at between 270 and 320 °C. (Pulse-heated soldering is not recommended for SO packages.)

For pulse-heated solder tool (resistance) soldering of VSO packages, solder is applied to the substrate by dipping or by an extra thick tin/lead plating before package placement.

AM/FM stereo radio circuit

TEA5711; TEA5711T

DEFINITIONS

| | |
|---|---|
| Data sheet status | |
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| Limiting values | |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | |
| Application information | |
| Where application information is given, it is advisory and does not form part of the specification. | |

LIFE SUPPORT APPLICATIONS

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AM/FM stereo radio circuit

TEA5711; TEA5711T

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